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Details

Product Status	Active
Core Processor	HC08
Core Size	8-Bit
Speed	8MHz
Connectivity	SCI
Peripherals	LVD, POR, PWM
Number of I/O	13
Program Memory Size	8KB (8K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	192 x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 4x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	16-SOIC (0.295", 7.50mm Width)
Supplier Device Package	16-SOIC
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=mc908kx8mdwe

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Chapter 7

Internal Clock Generator Module (ICG)

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Addr.	Register Name		Bit 7	6	5	4	3	2	1	Bit 0
\$FE05	Interrupt Status Register 2 (INT2) See page 150.	Read:	IF14	IF13	IF12	IF11	IF10	IF9	IF8	IF7
		Write:	R	R	R	R	R	R	R	R
		Reset:	0	0	0	0	0	0	0	0
\$FE06	Interrupt Status Register 3 (INT3) See page 150.	Read:	IF22	IF21	IF20	IF19	IF18	IF17	IF16	IF15
		Write:	R	R	R	R	R	R	R	R
		Reset:	0	0	0	0	0	0	0	0
\$FE07	FLASH Test Control Register (FLTCR)	Read:	R	R	R	R	R	R	R	R
		Write:								
		Reset:								
\$FE08	FLASH Control Register (FLCR) See page 31.	Read:	0	0	0	0	HVEN	MARGIN	ERASE	PGM
		Write:								
		Reset:	0	0	0	0	0	0	0	0
\$FE09	Break Address Register High (BRKH) See page 172.	Read:	Bit 15	14	13	12	11	10	9	Bit 8
		Write:								
		Reset:	0	0	0	0	0	0	0	0
\$FE0A	Break Address Register Low (BRKL) See page 172.	Read:	Bit 7	6	5	4	3	2	1	Bit 0
		Write:								
		Reset:	0	0	0	0	0	0	0	0
\$FE0B	Break Status and Control Register (BRKSCR) See page 171.	Read:	BRKE	BRKA	0	0	0	0	0	0
		Write:								
		Reset:	0	0	0	0	0	0	0	0
\$FE0C	LVI Status Register (LVISR) See page 103.	Read:	LVIOUT	0	0	0	0	0	0	R
		Write:								
		Reset:	0	0	0	0	0	0	0	0
\$FF7E	FLASH Block Protect Register (FLBPR) ⁽¹⁾ See page 36.	Read:	BPR7	BPR6	BPR5	BPR4	BPR3	BPR2	BPR1	BPR0
		Write:								
		Reset:	Unaffected by reset							

1. Non-volatile FLASH register

\$FFFF	COP Control Register (COPCTL) See page 53.	Read:	Low byte of reset vector									
		Write:	Writing clears COP counter (any value)									
		Reset:	Unaffected by reset									
		<div></div> = Unimplemented			<div>R</div> = Reserved			U = Unaffected				

Figure 2-2. Control, Status, and Data Registers (Sheet 5 of 5)

HVEN — High-Voltage Enable Bit

This read/write bit enables the charge pump to drive high voltages for program and erase operations in the array. HVEN can be set only if either PGM = 1 or ERASE = 1 and the proper sequence for program or erase is followed.

- 1 = High voltage enabled to array and charge pump on
- 0 = High voltage disabled to array and charge pump off

MASS — Mass Erase Control Bit

Setting this read/write bit configures the 8-Kbyte FLASH array for mass erase operation.

- 1 = MASS erase operation selected
- 0 = MASS erase operation unselected

ERASE — Erase Control Bit

This read/write bit configures the memory for erase operation. ERASE is interlocked with the PGM bit such that both bits cannot be equal to 1 or set to 1 at the same time.

- 1 = Erase operation selected
- 0 = Erase operation unselected

PGM — Program Control Bit

This read/write bit configures the memory for program operation. PGM is interlocked with the ERASE bit such that both bits cannot be equal to 1 or set to 1 at the same time.

- 1 = Program operation selected
- 0 = Program operation unselected

2.7 FLASH Page Erase Operation

Use this step-by-step procedure to erase a page (64 bytes) of FLASH memory to read as 1:

1. Set the ERASE bit and clear the MASS bit in the FLASH control register.
2. Read the FLASH block protect register.
3. Write any data to any FLASH location within the address range of the block to be erased.
4. Wait for a time, t_{NVS} (minimum 10 μ s).
5. Set the HVEN bit.
6. Wait for a time, t_{Erase} (minimum 1 ms or 4 ms).
7. Clear the ERASE bit.
8. Wait for a time, t_{NVH} (minimum 5 μ s).
9. Clear the HVEN bit.
10. After time, t_{RCV} (typical 1 μ s), the memory can be accessed in read mode again.

NOTE

While these operations must be performed in the order shown, other unrelated operations may occur between the steps.

In applications that require more than 1000 program/erase cycles, use the 4 ms page erase specification to get improved long-term reliability. Any application can use this 4 ms page erase specification. However, in applications where a FLASH location will be erased and reprogrammed less than 1000 times, and speed is important, use the 1 ms page erase specification to get a shorter cycle time.

2.9 FLASH Program/Read Operation

Programming of the FLASH memory is done on a row basis. A row consists of 32 consecutive bytes starting from addresses \$XX00, \$XX20, \$XX40, \$XX60, \$XX80, \$XXA0, \$XXC0, and \$XXE0. Use this step-by-step procedure to program a row of FLASH memory (Figure 2-4 is a flowchart representation).

NOTE

Only bytes which are currently \$FF may be programmed.

1. Set the PGM bit. This configures the memory for program operation and enables the latching of address and data for programming.
2. Read the FLASH block protect register.
3. Write any data to any FLASH location within the address range desired.
4. Wait for a time, t_{NVS} (minimum 10 μ s).
5. Set the HVEN bit.
6. Wait for a time, t_{PGS} (minimum 5 μ s).
7. Write data to the FLASH address being programmed⁽¹⁾.
8. Wait for time, t_{PROG} (minimum 30 μ s).
9. Repeat step 7 and 8 until all desired bytes within the row are programmed.
10. Clear the PGM bit⁽¹⁾.
11. Wait for time, t_{NVH} (minimum 5 μ s).
12. Clear the HVEN bit.
13. After time, t_{RCV} (typical 1 μ s), the memory can be accessed in read mode again.

This program sequence is repeated throughout the memory until all data is programmed.

NOTE

Programming and erasing of FLASH locations cannot be performed by code being executed from the FLASH memory. While these operations must be performed in the order shown, other unrelated operations may occur between the steps. Do not exceed t_{PROG} maximum. See 17.11 Memory Characteristics.

1. The time between each FLASH address change, or the time between the last FLASH address programmed to clearing PGM bit, must not exceed the maximum programming time, t_{PROG} maximum.

Central Processor Unit (CPU)

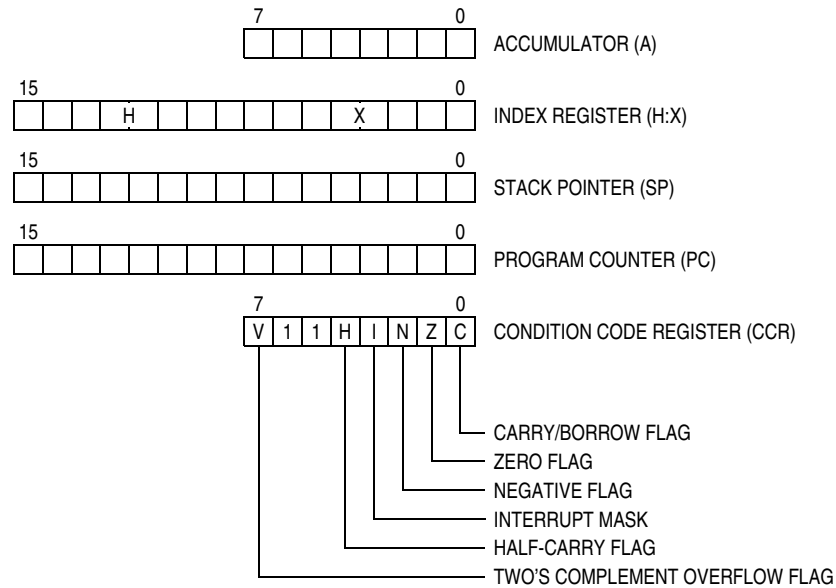


Figure 6-1. CPU Registers

6.3.1 Accumulator

The accumulator is a general-purpose 8-bit register. The CPU uses the accumulator to hold operands and the results of arithmetic/logic operations.

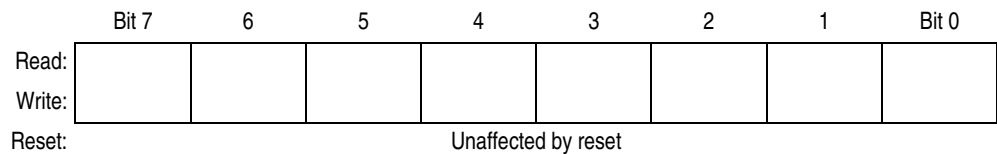


Figure 6-2. Accumulator (A)

6.3.2 Index Register

The 16-bit index register allows indexed addressing of a 64-Kbyte memory space. H is the upper byte of the index register, and X is the lower byte. H:X is the concatenated 16-bit index register.

In the indexed addressing modes, the CPU uses the contents of the index register to determine the conditional address of the operand.

The index register can serve also as a temporary data storage location.

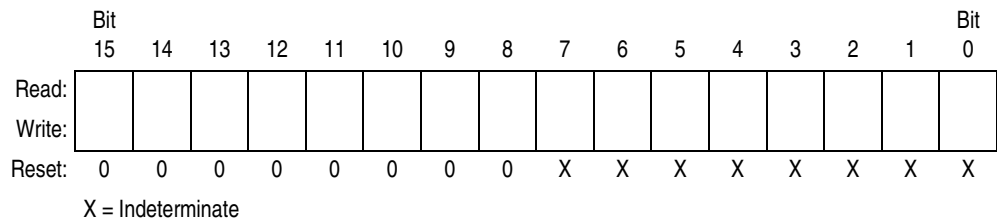


Figure 6-3. Index Register (H:X)

Chapter 12

Serial Communications Interface Module (SCI)

12.1 Introduction

The serial communications interface (SCI) allows asynchronous communications with peripheral devices and other microcontroller unit (MCU).

12.2 Features

The SCI module's features include:

- Full-duplex operation
- Standard mark/space non-return-to-zero (NRZ) format
- Choice of baud rate clock source:
 - Internal bus clock
 - CGMXCLK
- 32 programmable baud rates
- Programmable 8-bit or 9-bit character length
- Separately enabled transmitter and receiver
- Separate receiver and transmitter central processor unit (CPU) interrupt requests
- Programmable transmitter output polarity
- Two receiver wakeup methods:
 - Idle line wakeup
 - Address mark wakeup
- Interrupt-driven operation with eight interrupt flags:
 - Transmitter empty
 - Transmission complete
 - Receiver full
 - Idle receiver input
 - Receiver overrun
 - Noise error
 - Framing error
 - Parity error
- Receiver framing error detection
- Hardware parity checking
- 1/16 bit-time noise detection

Serial Communications Interface Module (SCI)

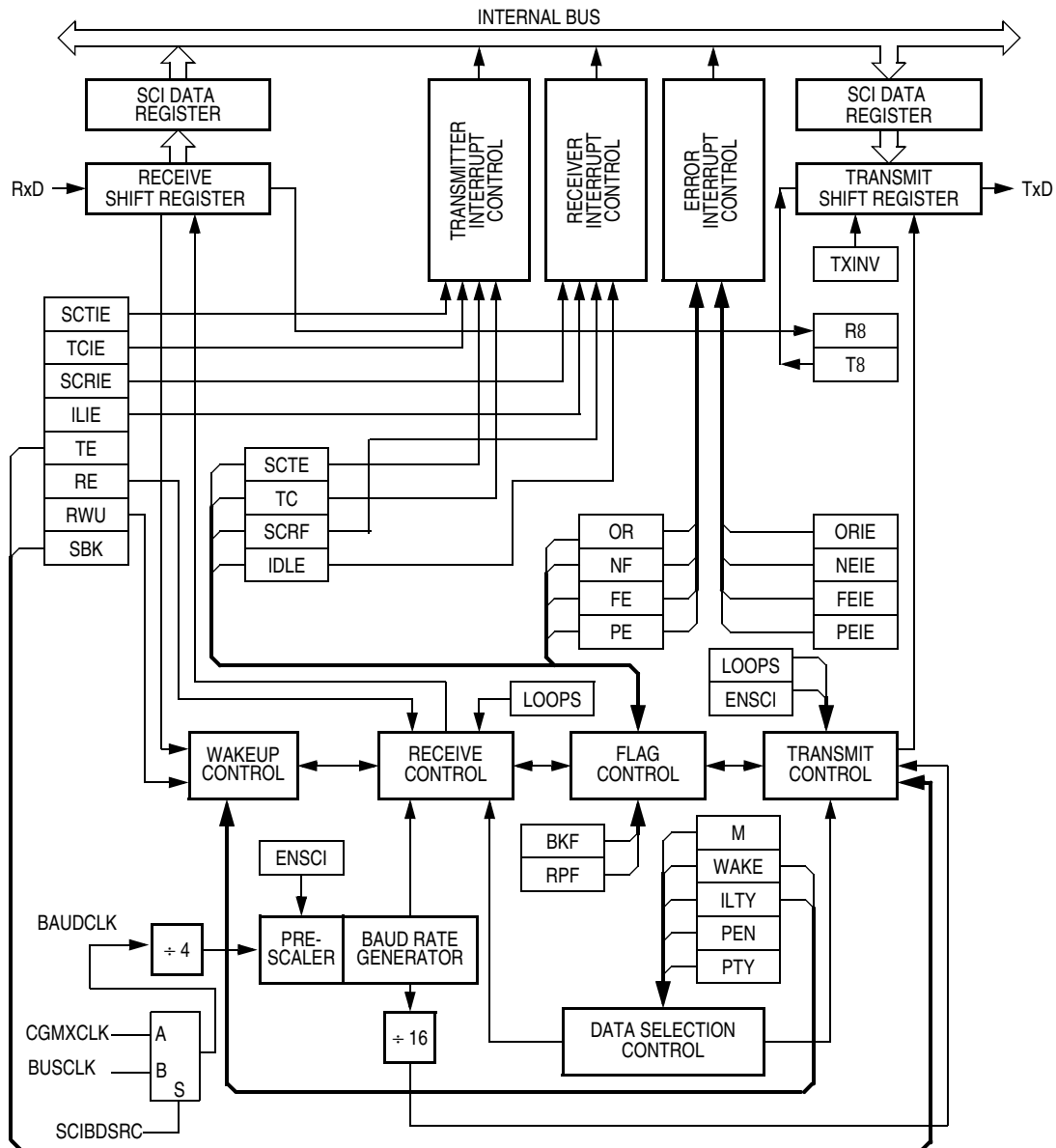


Figure 12-3. SCI Module Block Diagram

The maximum percent difference between the receiver count and the transmitter count of a fast 9-bit character with no errors is

$$\left| \frac{170 - 176}{170} \right| \times 100 = 3.53\%.$$

12.4.3.6 Receiver Wakeup

So that the MCU can ignore transmissions intended only for other receivers in multiple-receiver systems, the receiver can be put into a standby state. Setting the receiver wakeup bit, RWU, in SCC2 puts the receiver into a standby state during which receiver interrupts are disabled.

Depending on the state of the WAKE bit in SCC1, either of two conditions on the RxD pin can bring the receiver out of the standby state:

1. Address mark — An address mark is a 1 in the most significant bit position of a received character. When the WAKE bit is set, an address mark wakes the receiver from the standby state by clearing the RWU bit. The address mark also sets the SCI receiver full bit, SCRF. Software can then compare the character containing the address mark to the user-defined address of the receiver. If they are the same, the receiver remains awake and processes the characters that follow. If they are not the same, software can set the RWU bit and put the receiver back into the standby state.
2. Idle input line condition — When the WAKE bit is clear, an idle character on the RxD pin wakes the receiver from the standby state by clearing the RWU bit. The idle character that wakes the receiver does not set the receiver idle bit, IDLE, or the SCI receiver full bit, SCRF. The idle line type bit, ILTY, determines whether the receiver begins counting 1s as idle character bits after the start bit or after the stop bit.

NOTE

With the WAKE bit clear, setting the RWU bit after the RxD pin has been idle may cause the receiver to wake up immediately.

12.4.3.7 Receiver Interrupts

These sources can generate CPU interrupt requests from the SCI receiver:

- SCI receiver full (SCRF) — The SCRF bit in SCS1 indicates that the receive shift register has transferred a character to the SCDR. SCRF can generate a receiver CPU interrupt request. Setting the SCI receive interrupt enable bit, SCRIE, in SCC2 enables the SCRF bit to generate receiver CPU interrupts.
- Idle input (IDLE) — The IDLE bit in SCS1 indicates that 10 or 11 consecutive 1s shifted in from the RxD pin. The idle line interrupt enable bit, ILIE, in SCC2 enables the IDLE bit to generate CPU interrupt requests.

12.4.3.8 Error Interrupts

These receiver error flags in SCS1 can generate CPU interrupt requests:

- Receiver overrun (OR) — The OR bit indicates that the receive shift register shifted in a new character before the previous character was read from the SCDR. The previous character remains in the SCDR, and the new character is lost. The overrun interrupt enable bit, ORIE, in SCC3 enables OR to generate SCI error CPU interrupt requests.

13.2 SIM Bus Clock Control and Generation

The bus clock generator provides system clock signals for the CPU and peripherals on the MCU. The system clocks are generated from an incoming clock, CGMOUT, as shown in Figure 13-3. This clock originates from either an external oscillator or from the internal clock generator.

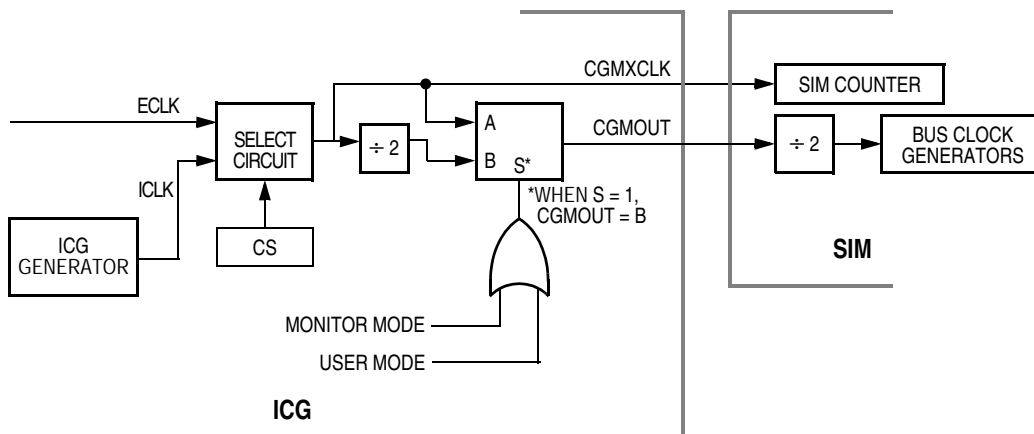


Figure 13-3. System Clock Signals

13.2.1 Bus Timing

In user mode, the internal bus frequency is the internal clock generator output (CGMXCLK) divided by four.

13.2.2 Clock Startup from POR or LVI Reset

When the power-on reset (POR) module or the low-voltage inhibit (LVI) module generates a reset, the clocks to the CPU and peripherals are inactive and held in an inactive phase until after 4096 CGMXCLK cycles. The MCU is held in reset by the SIM during this entire period. The bus clocks start upon completion of the timeout.

13.2.3 Clocks in Stop Mode and Wait Mode

Upon exit from stop mode by an interrupt or reset, the SIM allows CGMXCLK to clock the SIM counter. The CPU and peripheral clocks do not become active until after the stop delay timeout. Stop mode recovery timing is discussed in detail in 13.6.2 Stop Mode.

In wait mode, the CPU clocks are inactive. Refer to the wait mode subsection of each module to see if the module is active or inactive in wait mode. Some modules can be programmed to be active in wait mode.

13.7 SIM Registers

The SIM has four memory mapped registers described here.

1. SIM reset status register (SRSR)
2. Interrupt status register 1 (INT1)
3. Interrupt status register 2 (INT2)
4. Interrupt status register 2 (INT3)

13.7.1 SIM Reset Status Register

This register contains five bits that show the source of the last reset. The status register will clear automatically after reading it. A power-on reset sets the POR bit and clears all other bits in the register.

Address: \$FE01

	Bit 7	6	5	4	3	2	1	Bit 0
Read:	POR	0	COP	ILOP	ILAD	MENRST	LVI	0
Write:								
POR:	1	0	0	0	0	0	0	0


 = Unimplemented

Figure 13-16. SIM Reset Status Register (SRSR)

POR — Power-On Reset Bit

- 1 = Last reset caused by POR circuit
- 0 = Read of SRSR

COP — Computer Operating Properly Reset Bit

- 1 = Last reset caused by COP counter
- 0 = POR or read of SRSR

ILOP — Illegal Opcode Reset Bit

- 1 = Last reset caused by an illegal opcode
- 0 = POR or read of SRSR

ILAD — Illegal Address Reset Bit (opcode fetches only)

- 1 = Last reset caused by an opcode fetch from an illegal address
- 0 = POR or read of SRSR

MENRST — Forced Monitor Mode Entry Reset Bit

- 1 = Last reset was caused by the MENRST circuit
- 0 = POR or read of SRSR

LVI — Low-Voltage Inhibit Reset Bit

- 1 = Last reset was caused by the LVI circuit
- 0 = POR or read of SRSR

IF6 — Interrupt Flag 6

Since the MC68HC908KX8 parts do not use this interrupt flag, this bit will always read 0.

Bit 0 and Bit 1 — Always read 0

13.7.2.2 Interrupt Status Register 2

Address: \$FE05

	Bit 7	6	5	4	3	2	1	Bit 0
Read:	IF14	IF13	IF12	IF11	IF10	IF9	IF8	IF7
Write:	R	R	R	R	R	R	R	R
Reset:	0	0	0	0	0	0	0	0

R = Reserved

Figure 13-18. Interrupt Status Register 2 (INT2)

IF14–IF11 — Interrupt Flags 14–11

These flags indicate the presence of interrupt requests from the sources shown in Table 13-2.

1 = Interrupt request present

0 = No interrupt request present

IF10–IF7 — Interrupt Flags 10–7

Since the MC68HC908KX8 parts do not use these interrupt flags, these bits will always read 0.

13.7.2.3 Interrupt Status Register 3

Address: \$FE06

	Bit 7	6	5	4	3	2	1	Bit 0
Read:	IF22	IF21	IF20	IF19	IF18	IF17	IF16	IF15
Write:	R	R	R	R	R	R	R	R
Reset:	0	0	0	0	0	0	0	0

R = Reserved

Figure 13-19. Interrupt Status Register 3 (INT3)

IF22–IF17 — Interrupt Flags 22–17

Since the MC68HC908KX8 parts do not use these interrupt flags, these bits will always read 0.

IF16–IF15 — Interrupt Flags 16–15

These flags indicate the presence of interrupt requests from the sources shown in Table 13-2.

1 = Interrupt request present

0 = No interrupt request present

Timebase Module (TBM)

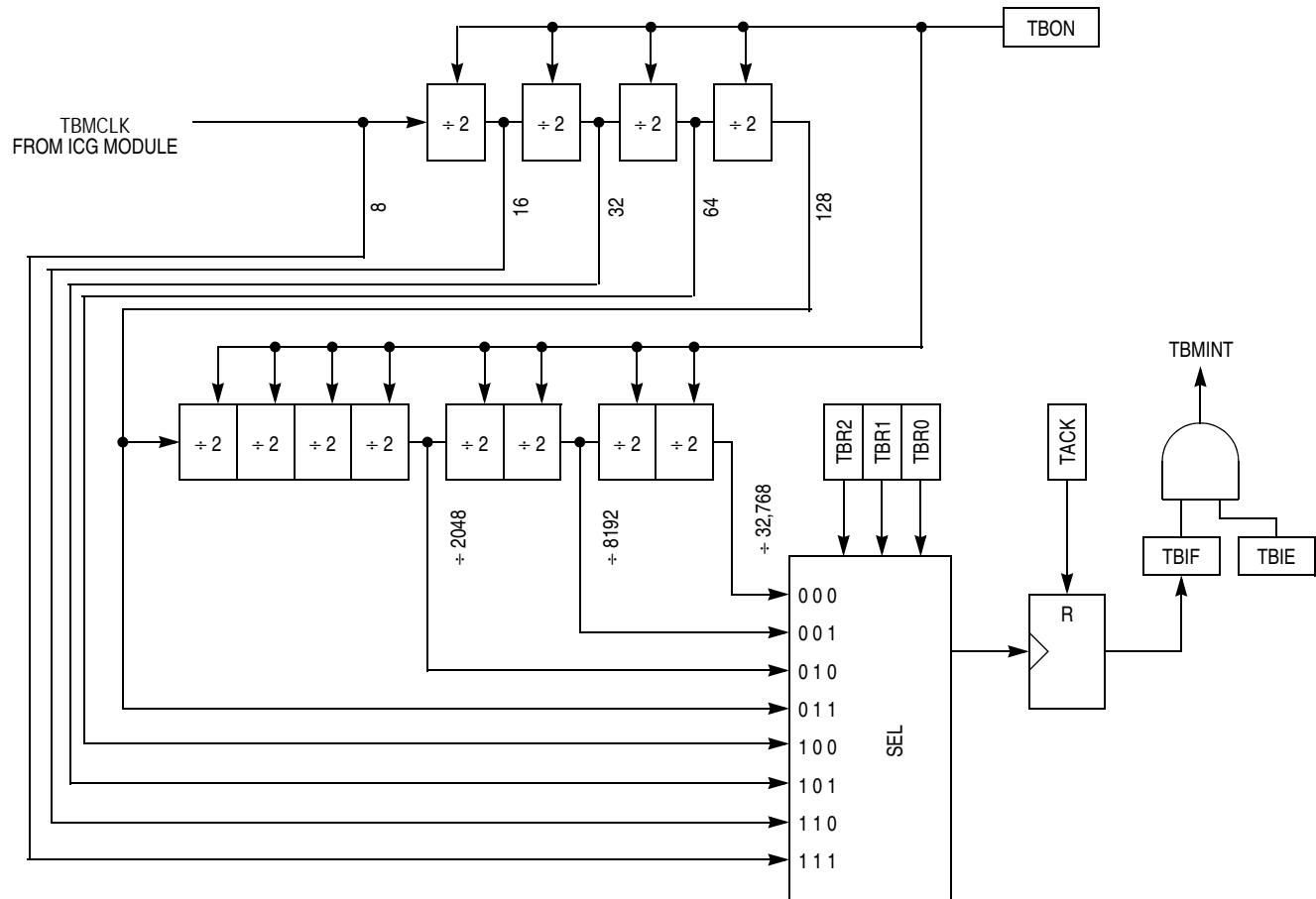


Figure 14-1. Timebase Block Diagram

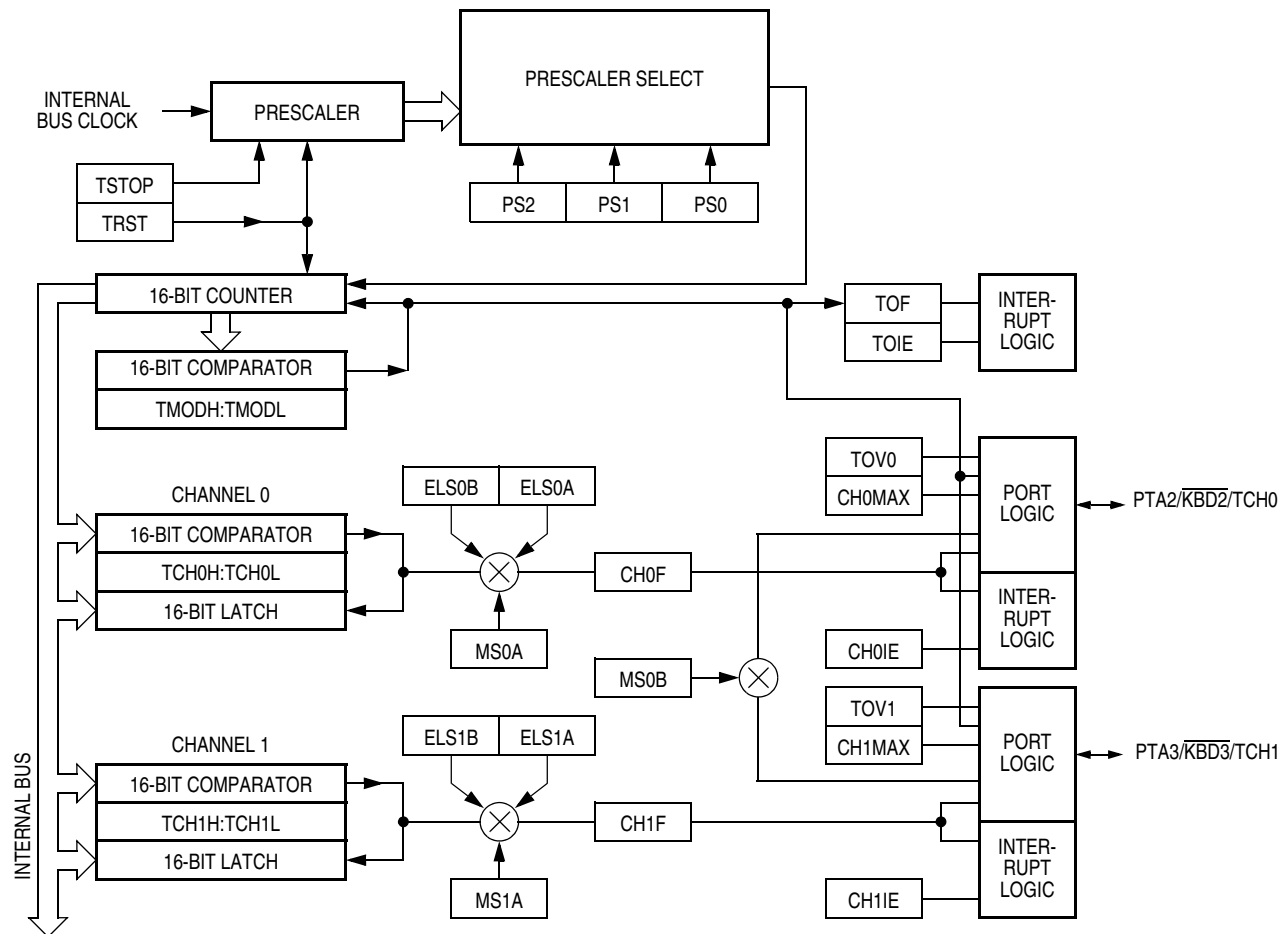


Figure 15-2. TIM Block Diagram

Addr.	Register Name	Bit 7	6	5	4	3	2	1	Bit 0
\$0020	Timer Status and Control Register (TSC) See page 163.	Read: TOF	TOIE	TSTOP	0	0	PS2	PS1	PS0
		Write: 0			TRST				
		Reset: 0	0	1	0	0	0	0	0
\$0021	Timer Counter Register High (TCNTH) See page 164.	Read: Bit 15	14	13	12	11	10	9	Bit 8
		Write:							
		Reset: 0	0	0	0	0	0	0	0
\$0022	Timer Counter Register Low (TCNTL) See page 164.	Read: Bit 7	6	5	4	3	2	1	Bit 0
		Write:							
		Reset: 0	0	0	0	0	0	0	0
\$0023	Timer Counter Modulo Register High (TMODH) See page 165.	Read: Bit 15	14	13	12	11	10	9	Bit 8
		Write:							
		Reset: 1	1	1	1	1	1	1	1

= Unimplemented

Figure 15-3. TIM I/O Register Summary

Timer Interface Module (TIM)

Addr.	Register Name		Bit 7	6	5	4	3	2	1	Bit 0
\$0024	Timer Counter Module Register Low (TMDL) See page 165.	Read:	Bit 7	6	5	4	3	2	1	Bit 0
		Write:								
		Reset:	1	1	1	1	1	1	1	1
\$0025	Timer Channel 0 Status and Control Register (TSC0) See page 165.	Read:	CH0F	CH0IE	MS0B	MS0A	ELS0B	ELS0A	TOV0	CH0MAX
		Write:	0							
		Reset:	0	0	0	0	0	0	0	0
\$0026	Timer Channel 0 Register High (TCH0H) See page 168.	Read:	Bit 15	14	13	12	11	10	9	Bit 8
		Write:								
		Reset:	Indeterminate after reset							
\$0027	Timer Channel 0 Register Low (TCH0L) See page 168.	Read:	Bit 7	6	5	4	3	2	1	Bit 0
		Write:								
		Reset:	Indeterminate after reset							
\$0028	Timer Channel 1 Status and Control Register (TSC1) See page 165.	Read:	CH1F	CH1IE	0	MS1A	ELS1B	ELS1A	TOV1	CH1MAX
		Write:	0							
		Reset:	0	0	0	0	0	0	0	0
\$0029	Timer Channel 1 Register High (TCH1H) See page 168.	Read:	Bit 15	14	13	12	11	10	9	Bit 8
		Write:								
		Reset:	Indeterminate after reset							
\$002A	Timer Channel 1 Register Low (TCH1L) See page 168.	Read:	Bit 7	6	5	4	3	2	1	Bit 0
		Write:								
		Reset:	Indeterminate after reset							


 = Unimplemented

Figure 15-3. TIM I/O Register Summary (Continued)

15.4.1 TIM Counter Prescaler

The TIM clock source can be one of the seven prescaler outputs. The prescaler generates seven clock rates from the internal bus clock. The prescaler select bits, PS2–PS0, in the TIM status and control register select the TIM clock source.

15.4.2 Input Capture

With the input capture function, the TIM can capture the time at which an external event occurs. When an active edge occurs on the pin of an input capture channel, the TIM latches the contents of the TIM counter into the TIM channel registers, TCHxH and TCHxL. The polarity of the active edge is programmable. Input captures can generate TIM CPU interrupt requests.

15.4.3 Output Compare

With the output compare function, the TIM can generate a periodic pulse with a programmable polarity, duration, and frequency. When the counter reaches the value in the registers of an output compare channel, the TIM can set, clear, or toggle the channel pin. Output compares can generate TIM CPU interrupt requests.

16.3.1.5 Data Format

The MCU waits for the host to send eight security bytes (see 16.3.2 Security). After the security bytes, the MCU sends a break signal (10 consecutive 0s) to the host computer, indicating that it is ready to receive a command.

Communication with the monitor ROM is in standard non-return-to-zero (NRZ) mark/space data format. Transmit and receive baud rates must be identical.

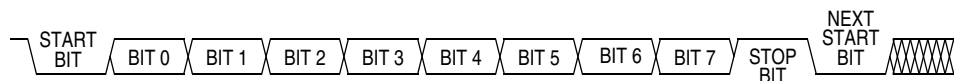


Figure 16-10. Monitor Data Format

16.3.1.6 Break Signal

A start bit (0) followed by nine 0 bits is a break signal. When the monitor receives a break signal, it drives the PTA0 pin high for the duration of two bits and then echoes back the break signal.

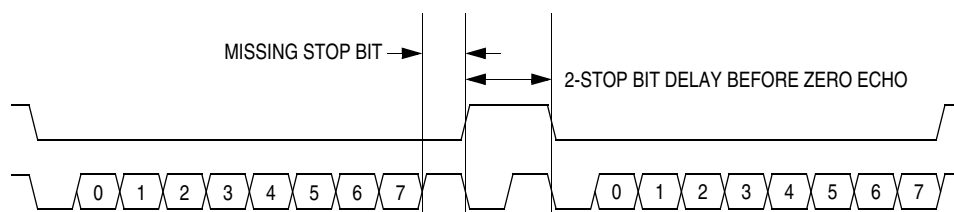


Figure 16-11. Break Transaction

16.3.1.7 Baud Rate

The communication baud rate is controlled by the CGMXCLK frequency output of the internal clock generator module.

16.3.1.8 Force Monitor Mode

In forced monitor mode, the baud rate is fixed at $\text{CGMXCLK}/1024$. A CGMXCLK frequency of 4.9152 MHz results in a 4800 baud rate. A 9.8304-MHz frequency produces a 9600 baud rate.

16.3.1.9 Normal Monitor Mode

In normal monitor mode, the communication baud rate is controlled by the CGMXCLK frequency output of the internal clock generator module. Table 16-3 lists CGMXCLK frequencies required to achieve standard baud rates. Other standard baud rates can be accomplished using other clock frequencies. The internal clock can be used as the clock source by programming the internal clock generator registers however, monitor mode will always be entered using the external clock as the clock source.

Table 16-3. Normal Monitor Mode Baud Rate Selection

CGMXCLK Frequency (MHz)	Baud Rate
9.8304	9600

16.3.1.10 Commands

The monitor ROM firmware uses these commands:

- READ, read memory
- WRITE, write memory
- IREAD, indexed read
- IWRITE, indexed write
- READSP, read stack pointer
- RUN, run user program

The monitor ROM firmware echoes each received byte back to the PTA0 pin for error checking. An 11-bit delay at the end of each command allows the host to send a break character to cancel the command. A delay of two bit times occurs before each echo and before READ, IREAD, or READSP data is returned. The data returned by a read command appears after the echo of the last byte of the command.

NOTE

Wait one bit time after each echo before sending the next byte.

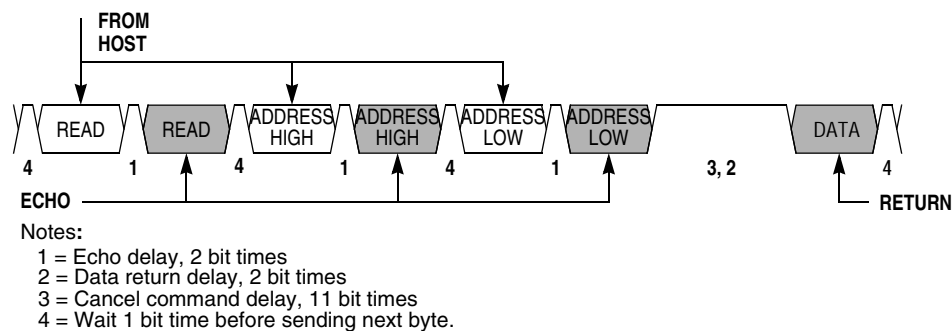


Figure 16-12. Read Transaction

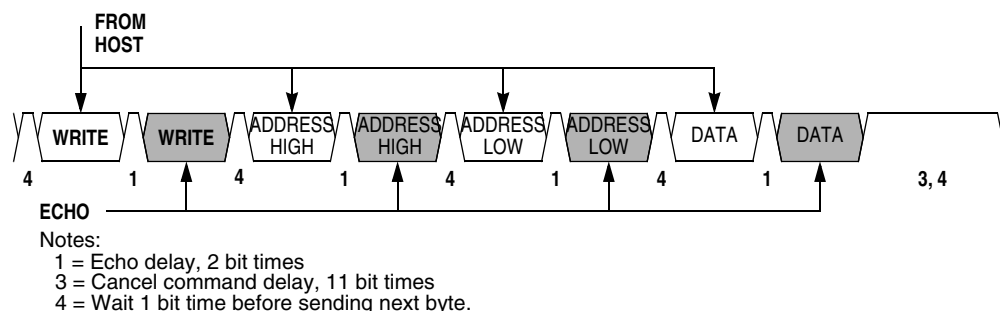


Figure 16-13. Write Transaction

Chapter 18

Ordering Information and Mechanical Specifications

18.1 Introduction

This section contains ordering numbers for MC68HC908KX8 and MC68HC908KX2. Refer to Figure 18-1 for an example of the device numbering system.

In addition, this section gives the package dimensions for:

- 16-pin plastic dual in-line package (case number 648D)
- 16-pin small outline package (case number 751G)

18.2 MC Order Numbers

Table 18-1. MC Order Numbers

MC Order Number ⁽¹⁾	Operating Temperature Range
MC68HC908KX8CP MC68HC908KX8CDW	–40°C to +85°C
MC68HC908KX8VP MC68HC908KX8VDW	–40°C to +105°C
MC68HC908KX8MP MC68HC908KX8MDW	–40°C to +125°C
MC68HC908KX2CP MC68HC908KX2CDW	–40°C to +85°C
MC68HC908KX2VP MC68HC908KX2VDW	–40°C to +105°C
MC68HC908KX2MP MC68HC908KX2MDW	–40°C to +125°C

1. P = Plastic dual in-line package
DW = Small outline package

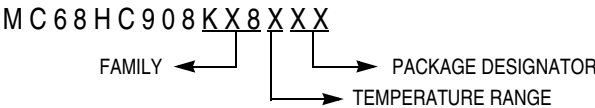
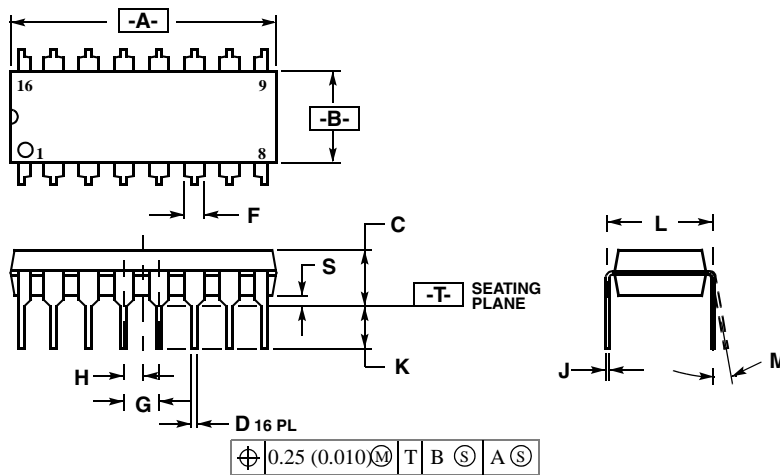


Figure 18-1. Device Numbering System

18.3 16-Pin Plastic Dual In-Line Package (PDIP)

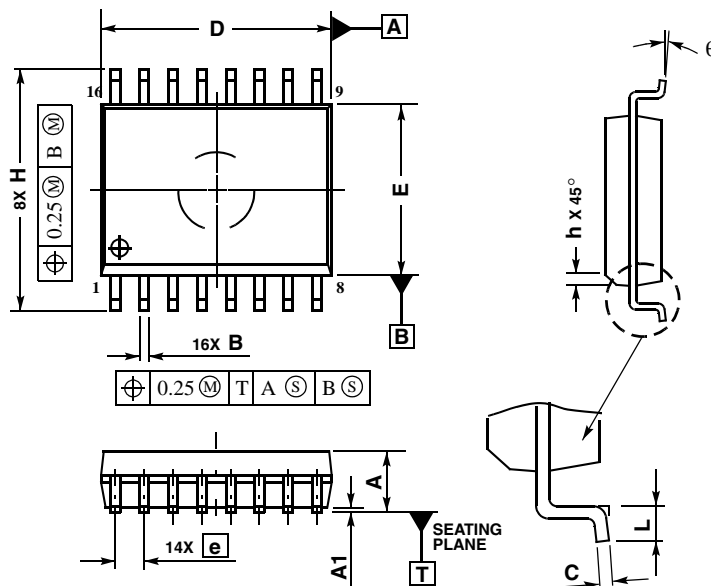


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
5. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.25 (0.010).
6. ROUNDED CORNERS OPTIONAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.740	0.760	18.80	19.30
B	0.245	0.260	6.23	6.60
C	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.050	0.070	1.27	1.77
G	0.100 BSC		2.54 BSC	
H	0.050 BSC		1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.120	0.140	3.05	3.55
L	0.295	0.305	7.50	7.74
M	0°	10°	0°	10°
S	0.015	0.035	0.39	0.88

18.4 16-Pin Small Outline Package (SOIC)



NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS	
	MIN	MAX
A	2.35	2.65
A1	0.10	0.25
B	0.35	0.49
C	0.23	0.32
D	10.15	10.45
E	7.40	7.60
e	1.27 BSC	
H	10.05	10.55
h	0.25	0.75
L	0.50	0.90
θ	0°	7°

Appendix B

MC68HC08KX8

B.1 Introduction

This appendix describes the differences between the read-only memory (ROM) version (MC68HC08KX8) and the FLASH version (MC68HC908KX8) of the microcontroller.

Basically, the differences are:

- FLASH x ROM module changes
 - FLASH for ROM substitution
 - Partial use of FLASH-related module
- Configuration register programming
- Wider range of operating voltage

B.2 FLASH x ROM Module Changes

This subsection describes changes between the FLASH and ROM modules.

B.2.1 FLASH for ROM Substitution

FLASH memory and FLASH supporting modules are replaced by ROM memory, see Figure B-1. In Figure B-1, the user FLASH and user FLASH vector space are respectively substituted by user ROM and user ROM vector space.

Additionally, these modules and registers have been eliminated in the ROM version:

- FLASH burn-in ROM module — Auxiliary FLASH routine codes
- FLASH charge pump module — High-voltage for FLASH programming
- MENRST module — Helps erased FLASH parts programming, see 13.3.1.5 Forced Monitor Mode Entry Reset (MENRST)
- SIM reset status register, bit 2 — Refers to MENRST. See 13.7.1 SIM Reset Status Register. MENRST has no function in the ROM version and reading this bit will return 0.
- FLASH test control register, FLTCR
- FLASH control register, FLCR
- FLASH block protect register, FLBPR

B.4 Electrical Specifications

This subsection contains electrical and timing specifications for the MC68HC08KX8.

B.4.1 Absolute Maximum Ratings

Maximum ratings are the extreme limits to which the microcontroller unit (MCU) can be exposed without permanently damaging it.

NOTE

This device is not guaranteed to operate properly at the maximum ratings. Refer to B.4.4 5.0-Vdc DC Electrical Characteristics, and for guaranteed operating conditions.

Characteristic ⁽¹⁾	Symbol	Value	Unit
Supply voltage	V_{DD}	−0.3 to +6.0	V
Input voltage	V_{In}	$V_{SS} - 0.3$ to $V_{DD} + 0.3$	V
Maximum current per pin Excluding V_{DD} , V_{SS} , and PTA0–PTA4	I	±15	mA
Maximum current for pins PTA0–PTA4	$I_{PTA0-IPTA4}$	±25	mA
Maximum current out of V_{SS}	I_{MVSS}	100	mA
Maximum current into V_{DD}	I_{MVDD}	100	mA
Storage temperature	T_{STG}	−55 to +150	°C

1. Voltages referenced to V_{SS}

NOTE

This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields; however, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum-rated voltages to this high-impedance circuit. For proper operation, it is recommended that V_{In} and V_{Out} be constrained to the range $V_{SS} \leq (V_{In} \text{ or } V_{Out}) \leq V_{DD}$. Reliability of operation is enhanced if unused inputs are connected to an appropriate logic voltage level (for example, either V_{SS} or V_{DD}).